

HMC334LP4 / 334LP4E

v03.0410



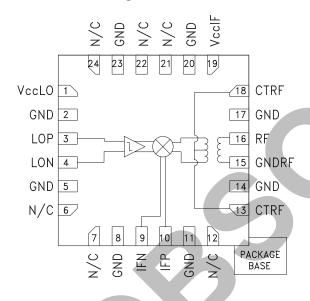
SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz

Typical Applications

The HM334LP4(E) is ideal for:

- Basestations & Repeaters
- GSM, GPRS & Edge
- CDMA, W-CDMA & TD-SCDMA
- WiMAX & LTE

Functional Diagram



Features

Conversion Loss: 0 dB LO to RF Isolation: 48 dB

Single-Ended LO Drive: -6 to +6 dBm

Input IP3: +26 dBm

SSB Noise Figure: 11 dB

On-Chip RF Balun

24 Lead 4x4mm QFN Package: 16 mm²

General Description

The HMC334LP4(E) is a low noise, wideband downconverter RFIC which is ideal for Cellular/3G and WiMAX/4G applications from 0.6 to 2.7 GHz. The LO input accepts drive levels from -6 to +6 dBm while the RFIC provides 48 dB of LO to RF isolation, and 0 dB conversion loss. The HMC334LP4(E) will support an IF output bandwidth of up to 600 MHz and consumes only 173 mA from a +5V supply. This wideband active mixer also provides excellent performance in the presence of high level "Blocker" signals, making it ideal for receiver applications in demanding environments.

Electrical Specifications,

 $T_A = +25 \, ^{\circ}\text{C}$, LO = 0 dBm*, Vslo = VsiF = +5V, IF = 240 MHz

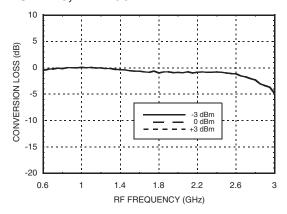
Parameter	Min.	Тур.	Max.	Units
Frequency Range, RF	0.6 - 2.7		GHz	
Frequency Range, LO	0.35 - 3.0 GHz		GHz	
Frequency Range, IF	1 - 600			MHz
Conversion Gain (IF XFMR Included)	-5	-1		dB
SSB Noise Figure		11		dB
LO to RF Isolation	30	48		dB
IF Output Impedance (Diff)		200		Ohms
IP3 (Input)		+26		dBm
1 dB Compression (Input)		12		dBm
LO Drive Input Level	-6 to +6 dBm		dBm	
Supply Current		173	225	mA

^{*}Unless otherwise noted all measurements with R1 = 13 Ohms and single-ended 50 Ohm IF output with Port J2 or J3 shorted to ground.

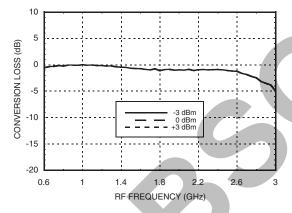




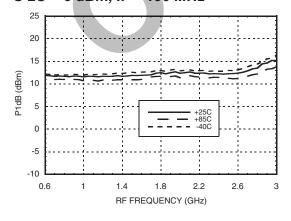
Conversion Gain vs. LO Drive, IF = 100 MHz [1]



Conversion Gain vs. LO Drive, IF = 240 MHz [1]

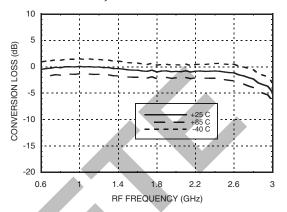


P1dB vs. Temperature @ LO = 0 dBm, IF = 100 MHz [1]

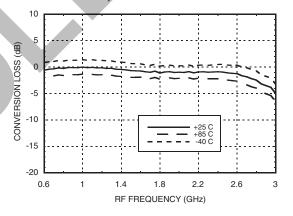


SiGe WIDEBAND **DOWNCONVERTER**, 0.6 - 2.7 GHz

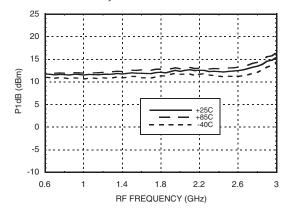
Conversion Gain vs. Temperature @ LO = 0 dBm, IF = 100 MHz [1]



Conversion Gain vs. Temperature @ LO = 0 dBm, IF = 240 MHz [1]



P1dB vs. Temperature @ LO = 0 dBm, IF = 240 MHz [1]



[1] LO < RF

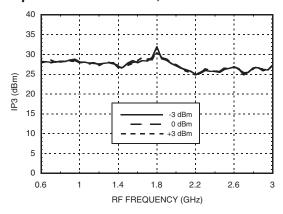
^{*} Unless otherwise noted all measurements with R1= 13 Ohms



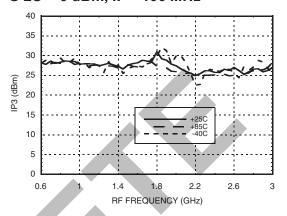


SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz

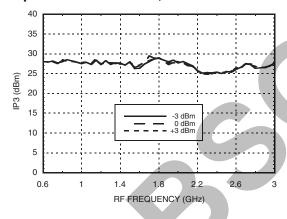
Input IP3 vs. LO Drive, IF = 100 MHz [1]



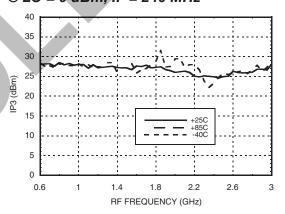
Input IP3 vs. Temperature @ LO = 0 dBm, IF = 100 MHz [1]



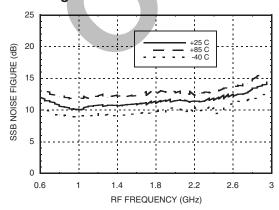
Input IP3 vs. LO Drive, IF = 240 MHz [1]



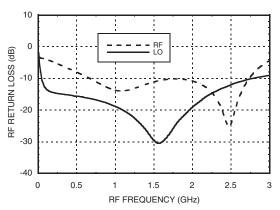
Input IP3 vs. Temperature @ LO = 0 dBm, IF = 240 MHz [1]



Noise Figure [1]



RF Return Loss @ LO = 0 dBm [1]



[1] LO < RF * Unless otherwise noted all measurements with R1= 13 Ohms

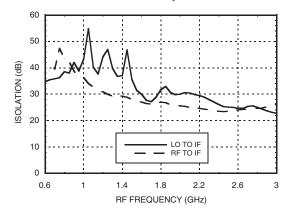
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



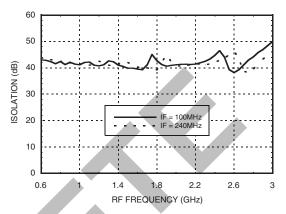


SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz

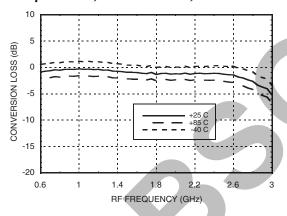
Isolation @ LO = 0 dBm, IF = 100 MHz [1]



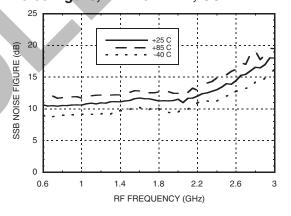
LO - RF Isolation @ LO = 0 dBm [1]



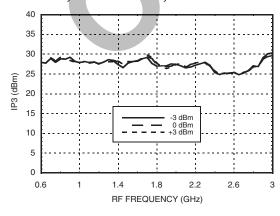
Conversion Gain vs.
Temperature, IF = 184 MHz, USB [2]



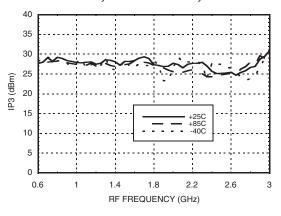
Noise Figure, IF = 184 MHz, USB [2]



Input IP3 vs. LO Drive, IF = 184 MHz, USB [2]



Input IP3 vs. Temperature @ LO = 0 dBm, IF = 184 MHz, USB [2]



[1] LO < RF [2] LO > RF





SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz

Absolute Maximum Ratings

RF Input (VsLo = VsIF= +5V)	+21 dBm
LO Drive (VsLo = VsIF= +5V)	+12 dBm
VccLO, VccIF	+6 Vdc
Channel Temperature	150 °C
Continuous Pdiss (T = 85°C) (derate 27.8 mW/°C above 85°C)	1.8 W
Thermal Resistance (channel to ground paddle)	36 °C/W
Storage Temperature	-65 to 150 °C
Operating Temperature	-40 to 85 °C

Typical Supply Current vs. Supply Voltage

VsLo = VsIF (V)	Islo + IsiF (mA)	
+4.5	146	
+5.0	173	
+5.5	200	
Downconverter will operate over full voltage range shown above.		



Outline Drawing

BOTTOM VIEW .161 4.10 .153 3.90 -.016 [0.40] REF .012 \[0.30 \] .007 \[0.18 \] .008 [0.20] MIN 19 PIN 1 HNNN XXXX 6 **EXPOSED** LOT NUMBER **GROUND PADDLE** 1.00 0.80 **SQUARE** 0.05 NOTES: SEATING 1. LEADFRAME MATERIAL: COPPER ALLOY PLANE 2. DIMENSIONS ARE IN INCHES [MILLIMETERS] △ .003[0.08] C 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE. -c-

- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC334LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H334 XXXX
HMC334LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H334 XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX





SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz

Pin Descriptions

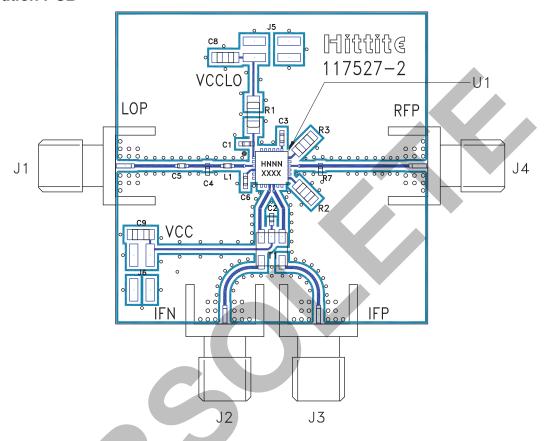
Pin Number	Function	Description	Interface Schematic
1	VccLO	Supply for LO Amplifier. Draws approximately 120mA from VSLO. A 13 Ohm resistor (R1) must be connected externally between the VSLO supply and the VccLO pin. See evaluation PCB schematic.	VecLO O LO DRIVE
2, 5, 8, 11, 14, 17, 20, 23	GND	These pins and the ground paddle should be connected to a high quality RF/DC ground.	GND
3	LOP	LO Input Port. This pin needs a DC blocking capacitor. (Typical voltage on this pin will be 1.5 - 1.8V)	VccL0 ○
4	LON	For single ended applications, this pin should be AC grounded	LON O
6, 7, 12, 21, 22, 24	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
9, 10	IFN, IFP	Differential baseband outputs, 200 ohm differential output impedance. Each port should draw approximately 25mA from VSIF without LO power and 28mA from VSIF with LO power on. For single-ended 50 Ohm operation, port J2 or J3 should be shorted to RF/DC ground. See evaluation PCB schematic.	VecilF VecilF O IFP
13, 18	CTRF	Center tap of the RF transformer. Biased at 2.2V when connected to ground through two 91 ohm resistors.	- OCTRF
15	GNDRF	Pin to be connected to a high quality RF/DC ground. Also can be used to drive the RF port differentially if needed.	3 E
16	RF	50 Ohms impedance can be matched from 600 - 3000 MHz.	3
19	VccIF	Supply decoupling for the mixer stage. (Typical voltage on this pin will be 4.8V) Connect C3 to a high quality RF/DC ground per evaluation PCB schematic.	VccIF O MIXER





SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz

Evaluation PCB



List of Materials for Evaluation PCB 117528 [1]

Item	Description
J1 - J4	Johnson SMA Connector
J5 - J6	2mm SMT
C1 - C3	1000 pF Capacitor, 0402 Pkg.
C4	0.3 pF Capacitor, 0402 Pkg.
C5	100 pF Capacitor, 0402 Pkg.
C6	10 KpF Capacitor, 0402 Pkg.
C7	1.3 pF Capacitor, 0402 Pkg.
C8, C9	0.1 μF Capacitor, 0805 Pkg.
L1	2.7 nH Chip Inductor, 0603 Pkg.
L2	2 nH Chip Inductor, 0603 Pkg.
R1	13 Ohm Resistor, 1206 Pkg.
R2, R3	91 Ohm Resistor, 0805 Pkg.
T1	M/A-Com 4:1 Balun, MABAES0061
U1	HMC334LP4 / HMC334LP4E
PCB [2]	117527 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB [2] Circuit Board Material: Rogers 4350

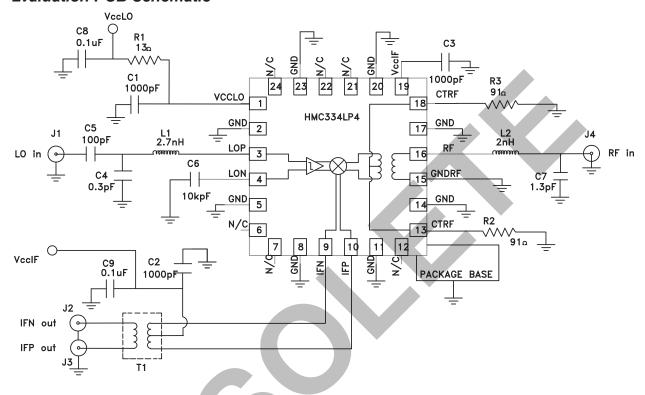
The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.



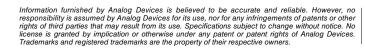


SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz

Evaluation PCB Schematic



Note: For single-ended 50 Ohms operation, port J2 or J3 should be shorted to RF/DC ground.



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Mixer category:

Click to view products by Analog Devices manufacturer:

Other Similar products are found below:

 M80C
 HMC337-SX
 F1763EVBI
 mamx-009646-23dbml
 HMC339-SX
 F1751NBGI
 CSM5T
 CHR3664-QEG
 NJM2552V-TE1

 HMC220BMS8GE
 HMC8192-SX
 LTC5569IUF#PBF
 HMC220BMS8GETR
 MAX2055EUP+TD
 M85C
 M74C
 CSM4TH
 HMC8191-SX

 CMD251C3
 MD-174-PIN
 CMD253C3
 HMC8192LG
 HMC553AG-SX
 HMC521A-SX
 HMC521ACHIPS
 HMC558A
 HMC553AG

 HMC8191
 MAMX-011023-SMB
 EMRS-1TR
 ADL5355ACPZ-R7
 HMC399MS8TR
 HMC141LH5
 HMC333TR
 HMC214MS8TR

 HMC175MS8TR
 HMC1043LC3TR
 F0552NLGI
 F1701NBGI
 F0502NLGI
 F1763NBGI
 MDS-189-PIN
 MAX2042AETP+
 MAX2032ETP+

 MAX2043ETX+
 CSM2-13
 CSM4T
 HMC1056LP4BETR
 LTC5510IUF#PBF
 LTC5553IUDB#TRMPBF